HD31114
SOLID STATE HIGH POWER AMPLIFIER

FEATURES

Class AB linear GaAsFET hybrid design
Instantaneous bandwidth
Suitable for all single channel modulation standards
Built-in protection circuits
High reliability and ruggedness



ELECTRICAL SPECIFICATIONS

Parameter	Specification	Notes
Operating Frequency Range	26.0 - 31.0 GHz	
Power Output @ Psat	5 Watt Min	
Power Output P1dB GCP	4 Watt Min	
Power Gain	37 dB Min	
Power Gain Flatness	4.0 dB p-p Max	Constant input power
Input / Output Return Loss	-10 dB Max	Relative to 50 Ohm
Noise Figure	12 dB Max	
Harmonics	-20 dBc Max	At rated Pout
Spurious	-60 dBc Max	Non-harmonics
Operating Voltage	9 VDC Nom	
Current Consumption	10 Amp Max / 7 Amp Typ	At rated Pout
Input Power Protection	+3 dBm Max	<10 Sec without damage
Load VSWR Protection	5 : 1 Max	<1 minute at rated Pout

ENVIRONMENTAL CHARACTERISTICS

Parameter	Specification	Notes
Operating Case Temperature	-20 to +65 °C	
Storage Temperature	-40 to +85 °C	
Relative Humidity	5 to 95 %	Non-condensing

MECHANICAL SPECIFICATIONS

Parameter	Specification	Notes
Dimensions	100 x 110 x 27 mm	Excluding connectors
Weight	600 gr.	
RF Connectors In/Out	SMA K Type female	
DC Power / Interface Connector	9-Pin D-Sub	
Cooling	External Heatsink	Forced air required

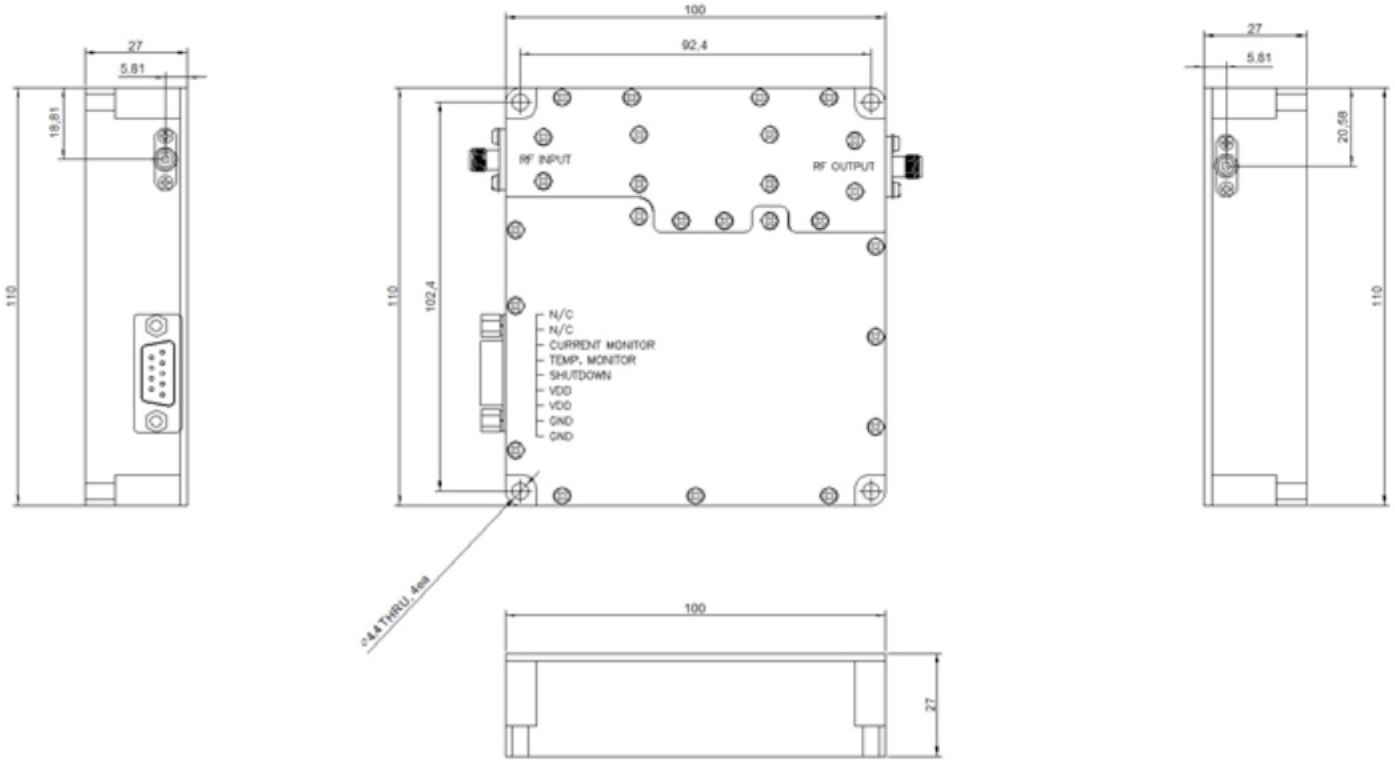
D-SUB CONNECTOR PIN ASSIGNMENT

Pin	Function	Description
1	N/C	Reserved
2	N/C	Reserved
3	CURRENT SENSOR	I_D@20mV/100mA Typ
4	TEMP SENSOR	V_T@10mV/°C + 500mV Typ
5	SHUTDOWN	TTL
6, 7	VDD	9VDC
8, 9	GND	Ground

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Specifications subject to change without notice. Specifications and drawings may vary with selected options.

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OUTLINE DRAWING



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